



DMN6075SQ

#### Summary

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max I <sub>D</sub> Max T <sub>A</sub> = +25°				
60V	85mΩ @ V <sub>GS</sub> = 10V	2.5A			
607	120mΩ @ $V_{GS}$ = 4.5V	2.0A			

# **Description and Applications**

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Backlighting

# Features and Benefits

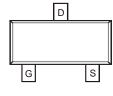
- N MOSFET
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMN6075SQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

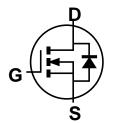
**60V N-CHANNEL ENHANCEMENT MODE MOSFET** 

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)







Top View

Top View

Equivalent Circuit

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN6075SQ-7	SOT23	3000/Tape & Reel
DMN6075SQ-13	SOT23	10000/Tape & Reel

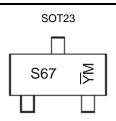
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



 $\frac{S67}{YM} = Product Type Marking Code$  $\frac{YM}{Y} = Date Code Marking$  $\frac{Y}{Y} = Year (ex: G = 2019)$ M = Month (ex: 9 = September)

#### Date Code Key

Bale Code He	<b>y</b>											
Year	2019	2020	20	021	2022	2023	3	2024	2025	20	26	2027
Code	G	Н			J	K		L	М	Ν	l	0
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Continuous Durin Current (Nata 5) // 10//	Steady	T <sub>A</sub> = +25°C	1	2.0	٨
Continuous Drain Current (Note 5) $V_{GS} = 10V$	State	T <sub>A</sub> = +70°C	ID	1.5	A
	Steady	T <sub>A</sub> = +25°C	١ <sub>D</sub>	2.5	٨
Continuous Drain Current (Note 6) $V_{GS} = 10V$	State	T <sub>A</sub> = +70°C		2.0	A
Maximum Body Diode Forward Current (Note 5)			ls	2.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 19	6)	I <sub>DM</sub>	12	А	
Pulsed Source Current (10µs Pulse, Duty Cycle =	1%)	I <sub>SM</sub>	12	А	

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	D-	0.8	W	
Total Power Dissipation (Note 5)	$T_A = +70^{\circ}C$	PD	0.5		
Thermal Resistance, Junction to Ambient (Note 5) Steady State		$R_{ ext{ heta}JA}$	157	°C/W	
Tatal Dower Dissinction (Nate 6)	T <sub>A</sub> = +25°C	P	1.15	10/	
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	0.7	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ ext{ heta}JA}$	110	°C/W	
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>		—	1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>		—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	•					
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Statia Drain Course On Desistance			69	85		V <sub>GS</sub> = 10V, I <sub>D</sub> = 3.2A
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		75	120	mΩ	$V_{GS} = 4.5V, I_D = 2.8A$
Diode Forward Voltage	V <sub>SD</sub>		0.8	1.2	V	$V_{GS} = 0V, I_{S} = 2.5A$
DYNAMIC CHARACTERISTICS (Note 8)	•					
Input Capacitance	C <sub>iss</sub>	_	606	_	pF	
Output Capacitance	Coss		32.6	—	pF	<sup>−</sup> V <sub>DS</sub> = 20V, V <sub>GS</sub> = 0V, −f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>		24.6	—	pF	
Gate Resistance	Rg		1.5		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg		12.3	_	nC	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg		5.6	_	nC	
Gate-Source Charge	Q <sub>gs</sub>	_	1.7		nC	$V_{DS} = 30V, I_D = 3A$
Gate-Drain Charge	Q <sub>gd</sub>		1.9		nC	
Turn-On Delay Time	t <sub>D(ON)</sub>		3.5	_	ns	
Turn-On Rise Time			4.1	_	ns	V <sub>GS</sub> = 10V, V <sub>DS</sub> = 30V,
Turn-Off Delay Time	t <sub>D(OFF)</sub>		35	—	ns	$R_g = 20\Omega, R_L = 50\Omega$
Turn-Off Fall Time	t <sub>F</sub>	_	11	_	ns	7

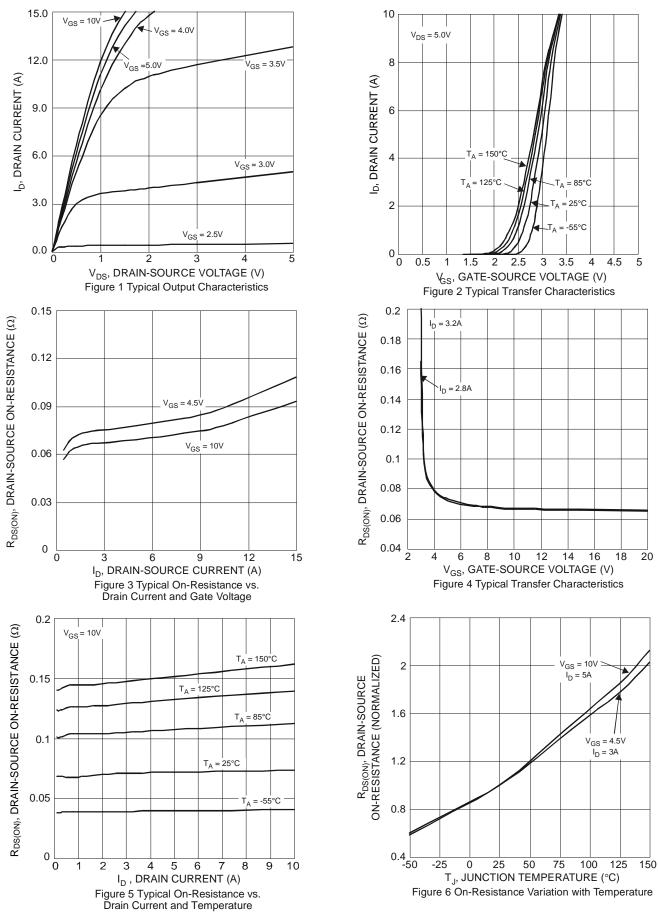
Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal vias to bottom layer 1-inch square copper plate.

7. Short duration pulse test used to minimize self-heating effect.

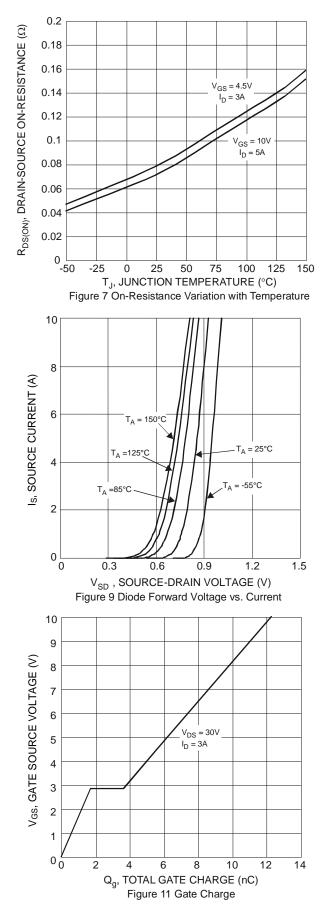
8. Guaranteed by design. Not subject to product testing.





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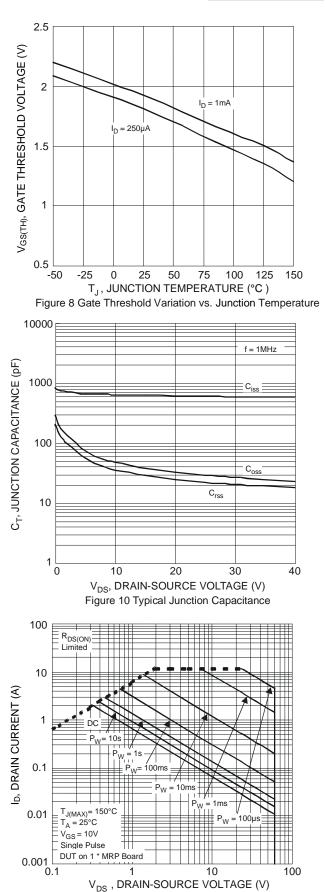
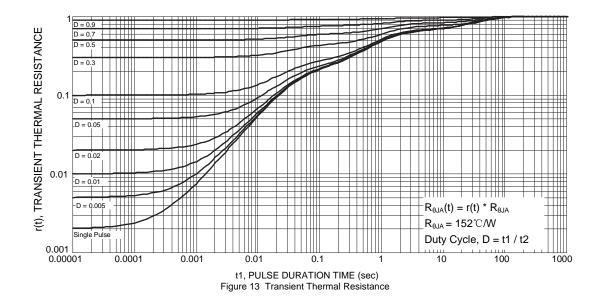


Figure 12 SOA, Safe Operation Area

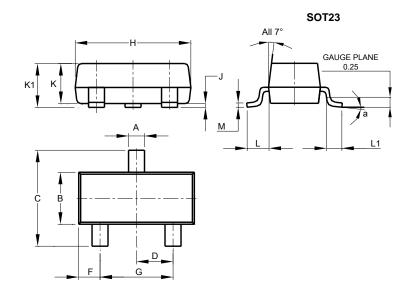






# **Package Outline Dimensions**

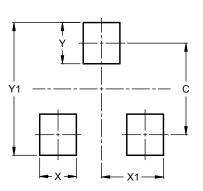
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
К	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)				
С	2.0				
Х	0.8				
X1	1.35				
Y	0.9				
Y1	2.9				

SOT23



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